

Trench IGBT Modules

SKM 600GB066D

Features

- Trench = Trenchgate technology
- V_{CE(sat)} with positive temperature coefficient
- High short circuit capability, self limiting to 6 x I_C

Typical Applications*

- AC inverter drives
- UPS
- · Electronic welders

Remarks

- Case temp. limited. to T = 125°C, recomm. T_{op} = -40 ... +150°C, product rel. results valid for T_i≤150°C
- SC data: $t_p \le 6$ s; $V_{GE} \le 15V$; T_j = 150°C; $V_{cc} \le 360V$, use of soft R_G necessary!
- Take care of over-voltage caused by stray induct.
- I_{DC}≤500A for T_{Terminal}=100°C

Absolute Maximum Ratings T _{case} = 25°C, unless otherwise specified							
Symbol	Conditions		Values	Units			
IGBT				_			
V_{CES}	T _j = 25 °C		600	V			
I _C	T _j = 175 °C	T _c = 25 °C	760	Α			
		$T_c = 80 ^{\circ}C$	570	Α			
I _{CRM}	I _{CRM} =1,33xI _{Cnom}		800	Α			
V_{GES}			±20	V			
t _{psc}	V_{CC} = 360 V; $V_{GE} \le 15$ V; VCES < 600 V	T _j = 150 °C	6	S			
Inverse Diode				•			
I _F	T _j = 175 °C	$T_c = 25 ^{\circ}C$	700	Α			
		$T_c = 80 ^{\circ}C$	510	Α			
I _{FRM}	I _{FRM} =1,33xI _{Fnom}		800	Α			
Module							
I _{t(RMS)}			500	Α			
T _{vj}			- 40 + 175	°C			
T _{stg}			- 40 + 125	°C			
V _{isol}	AC, 1 min.		4000	V			

Characteristics T _{case}		= 25°C, unless otherwise specified				
Symbol	Conditions		min.	typ.	max.	Units
IGBT						
$V_{GE(th)}$	$V_{GE} = V_{CE}$, $I_C = 9.6$ mA		5	5,8	6,5	V
I _{CES}	$V_{GE} = 0 V, V_{CE} = V_{CES}$	T _j = 25 °C		0,3	0,9	mA
V _{CE0}		T _j = 25 °C		0,9	1	V
		T _j = 150 °C		0,85	0,9	V
r _{CE}	V _{GE} = 15 V	T _j = 25°C		0,9	1,5	mΩ
		T _j = 150°C		1,4	2	mΩ
V _{CE(sat)}	I _{Cnom} = 600 A, V _{GE} = 15 V			1,45	1,9	V
		$T_j = 150^{\circ}C_{chiplev.}$		1,7	2,1	V
C _{ies}				37		nF
C _{oes}	$V_{CE} = 25, V_{GE} = 0 V$	f = 1 MHz		2,3		nF
C _{res}				1,1		nF
Q_G	V _{GE} = -8V+15V			4400		nC
R_{Gint}	T _j = °C			0,5		Ω
t _{d(on)}				270		ns
t _r E _{on}	R_{Gon} = 1,5 Ω	V _{CC} = 300V		77		ns
E _{on}	D 450	I _C = 600A		7,5		mJ
t _{d(off)}	$R_{Goff} = 1.5 \Omega$	T _j = 150 °C		670		ns
t _f		$V_{GE} = -8V/+15V$		77		ns
E _{off}				29,5		mJ
$R_{th(j-c)}$	per IGBT				0,08	K/W





Characteristics

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Symbol	Conditions		min.	tvn	max.	Units
_			1111111.	typ.	IIIax.	Ullits
Inverse D	i .		i			i
$V_F = V_{EC}$	$I_{Fnom} = 600 \text{ A}; V_{GE} = 0 \text{ V}$	$T_j = 25 ^{\circ}C_{\text{chiplev.}}$		1,4	1,6	V
V_{F0}		T _j = 25 °C		0,95	1	V
r _F		T _j = 25 °C		0,8	1	mΩ
I _{RRM}	I _F = 600 A	T _i = 150 °C		580		Α
Q _{rr}	di/dt = 8600 A/ s	,		105		С
E _{rr}	V_{GE} = -8 V; V_{CC} = 300 V			25		mJ
$R_{th(j-c)D}$	per diode				0,125	K/W
Module						
L _{CE}				15	20	nΗ
R _{CC'+EE'}	res., terminal-chip	T _{case} = 25 °C		0,35		mΩ
		T _{case} = 125 °C		0,5		mΩ
R _{th(c-s)}	per module				0,038	K/W
M_s	to heat sink M6		3		5	Nm
M _t	to terminals M6		2,5		5	Nm
w					325	g

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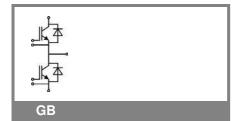
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This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.





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Z _{th}	Conditions	Values	Hnito
	Conditions	values	Units
${f Z}_{{\sf R}_{\sf i}}$			•
R _i	i = 1	48,4	mk/W
R _i	i = 2	19,5	mk/W
R_i	i = 3	3,1	mk/W
R_{i}	i = 4	4	mk/W
tau _i	i = 1	0,054	s
taui	i = 2	0,0144	s
taui	i = 3	0,0012	s
tau _i	i = 4	0,0026	s
Z _{the} /; a\D			
Z _{th(j-c)D}	i = 1	80	mk/W
R _i	i = 2	33	mk/W
R_{i}	i = 3	10,5	mk/W
R _i	i = 4	1,5	mk/W
tau _i	i = 1	0,054	s
tau _i	i = 2	0,01	s
tau _i	i = 3	0,0007	s
tau _i	i = 4	0,0019	s

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